## EAST Search History

| Ref<br># | Hits | Search Query  | DBs      | Default<br>Operator | Plurals | Time Stamp       |
|----------|------|---|----------|---------------------|---------|------------------|
| L1       | 0    | (semiconductor and device and comprising and interconnection and board and having and first and second and surfaces and multilevel and insulating and resin and layer and therein and least and one and external and electrode and pad and buried).clm. | US-PGPUB | OR                  | ON      | 2006/12/23 20:04 |